



STPS20170C

HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

Table 1: Main Product Characteristics

$I_{F(AV)}$	2 x 10 A
V_{RRM}	170 V
T_j	175°C
$V_F(max)$	0.75 V

Features

- High reverse voltage
- High junction temperature capability
- Avalanche specification with derating curves

Benefits

- Can challenge bipolar ultrafast diodes with better dynamic characteristics.

Description

Dual center tap Schottky rectifier diode suited for high frequency switched mode power supplies.

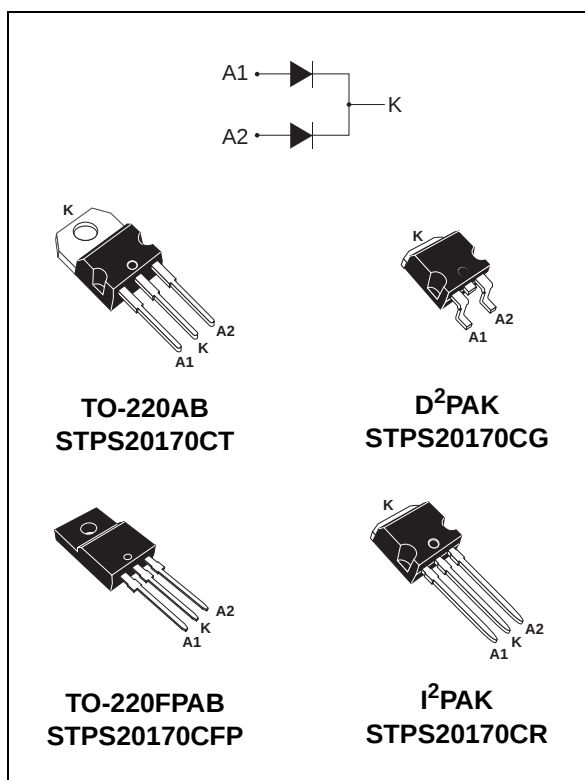


Table 2: Order Codes

Part Numbers	Marking
STPS20170CT	STPS20170CT
STPS20170CFP	STPS20170CFP
STPS20170CR	STPS20170CR
STPS20170CG	STPS20170CG
STPS20170CG-TR	STPS20170CG

Table 3: Absolute Ratings (limiting values, per diode)

Symbol	Parameter				Value	Unit
V _{RRM}	Repetitive peak reverse voltage				170	V
I _{F(RMS)}	RMS forward voltage				30	A
I _{F(AV)}	Average forward current δ = 0.5	TO-220AB / D ² PAK / I ² PAK	T _c = 155°C	Per diode Per device	10 20	A
		TO-220FPAB	T _c = 135°C	Per diode Per device	10 20	
I _{FSM}	Surge non repetitive forward current		t _p = 10ms sinusoidal		180	A
P _{ARM}	Repetitive peak avalanche power		t _p = 1μs T _j = 25°C		6700	W
T _{stg}	Storage temperature range				-65 to + 175	°C
T _j	Maximum operating junction temperature *				175	°C
dV/dt	Critical rate of rise of reverse voltage				10000	V/μs

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

Table 4: Thermal Parameters

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AB / D ² PAK / I ² PAK	Per diode Total	2.2 1.3	$^\circ\text{C/W}$
		TO-220FPAB	Per diode Total	4.5 3.5	
$R_{th(c)}$		TO-220AB / D ² PAK / I ² PAK	Coupling	0.3	
		TO-220FPAB		2.5	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

Table 5: Static Electrical Characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ	Max.	Unit
I_R *	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			15	μA
		$T_j = 125^\circ\text{C}$				15	mA
V_F **	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 10\text{A}$			0.90	V
		$T_j = 125^\circ\text{C}$			0.69	0.75	
		$T_j = 25^\circ\text{C}$	$I_F = 20\text{A}$			0.99	
		$T_j = 125^\circ\text{C}$			0.79	0.86	

Pulse test: * $t_p = 5\text{ ms}$, $\delta < 2\%$

** $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation: $P = 0.64 \times I_{F(AV)} + 0.011 I_{F(RMS)}^2$

Figure 1: Average forward power dissipation versus average forward current (per diode)

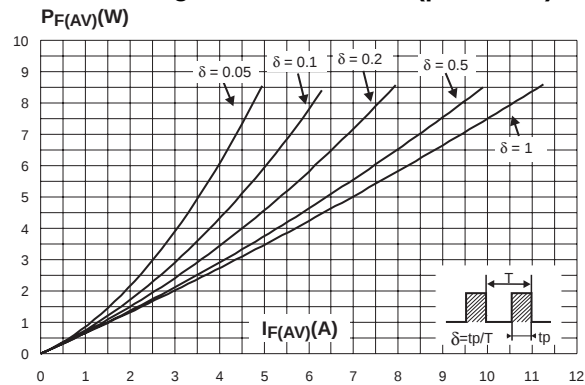


Figure 2: Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

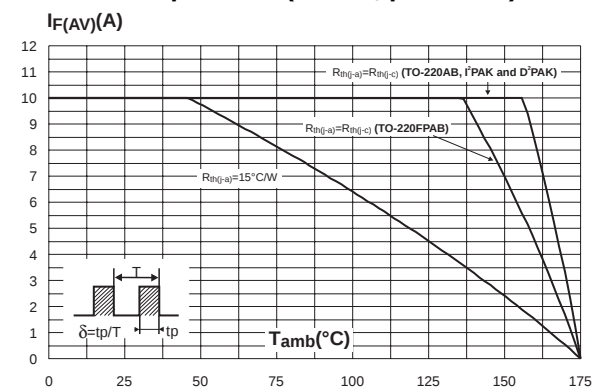


Figure 3: Normalized avalanche power derating versus pulse duration

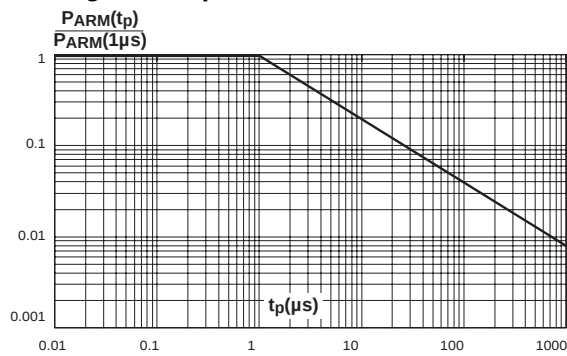


Figure 4: Normalized avalanche power derating versus junction temperature

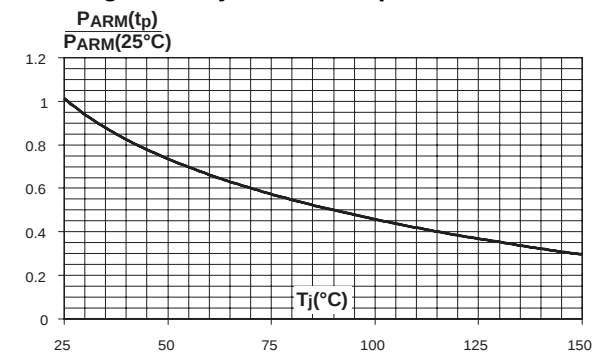


Figure 5: Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220AB, D²PAK, I²PAK)

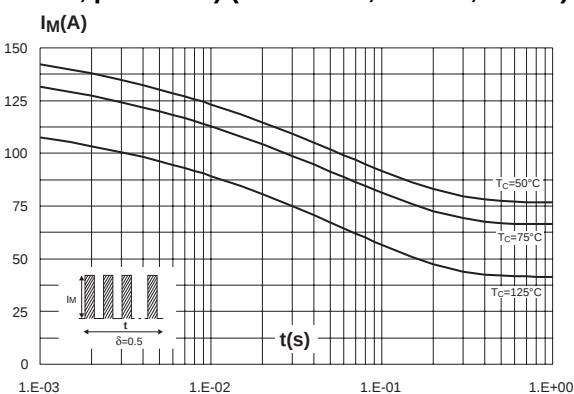


Figure 6: Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220FPAB)

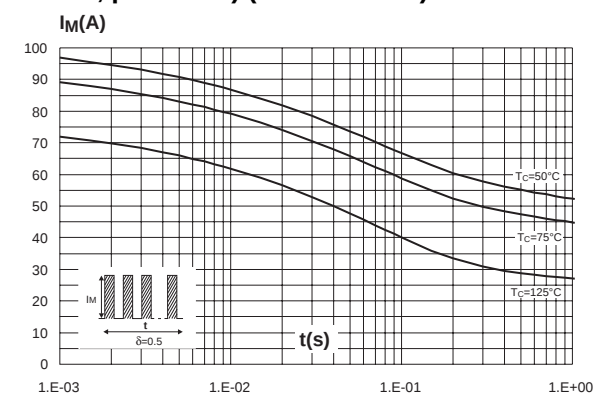


Figure 7: Relative variation of thermal impedance junction to case versus pulse duration

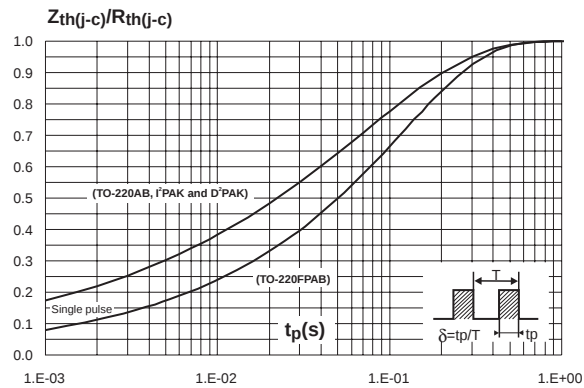


Figure 8: Reverse leakage current versus reverse voltage applied (typical values, per diode)

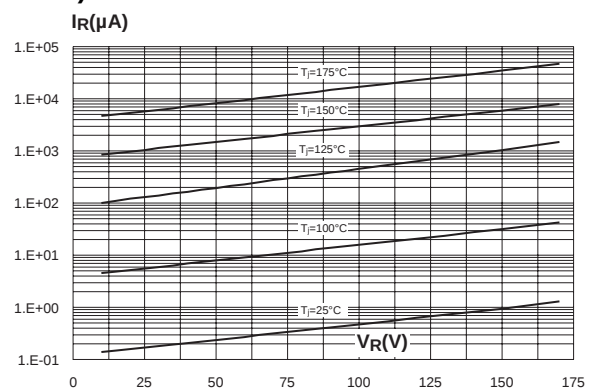


Figure 9: Junction capacitance versus reverse voltage applied (typical values, per diode)

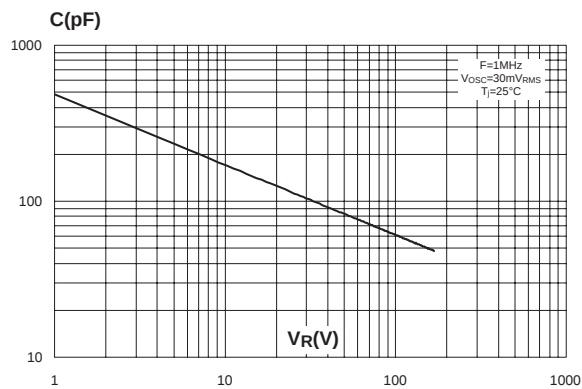


Figure 10: Forward voltage drop versus forward current (per diode)

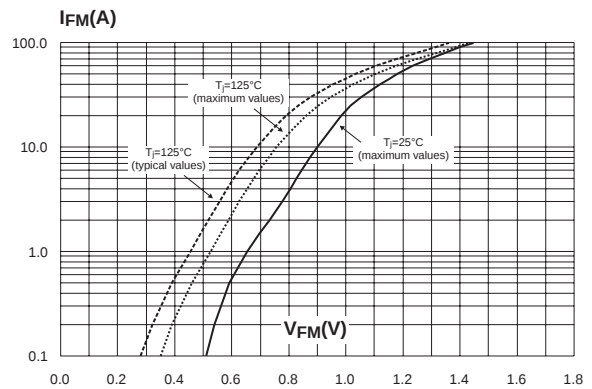


Figure 11: Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4, Cu = 35μm) (D²PAK)

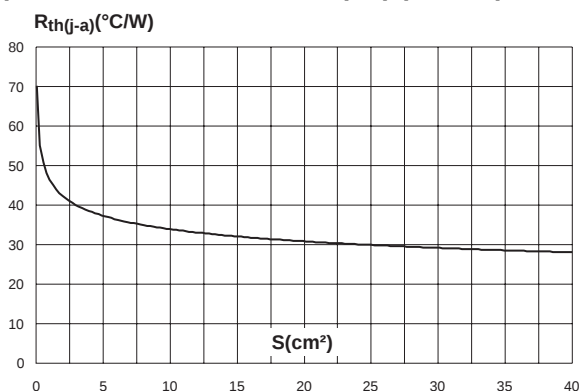


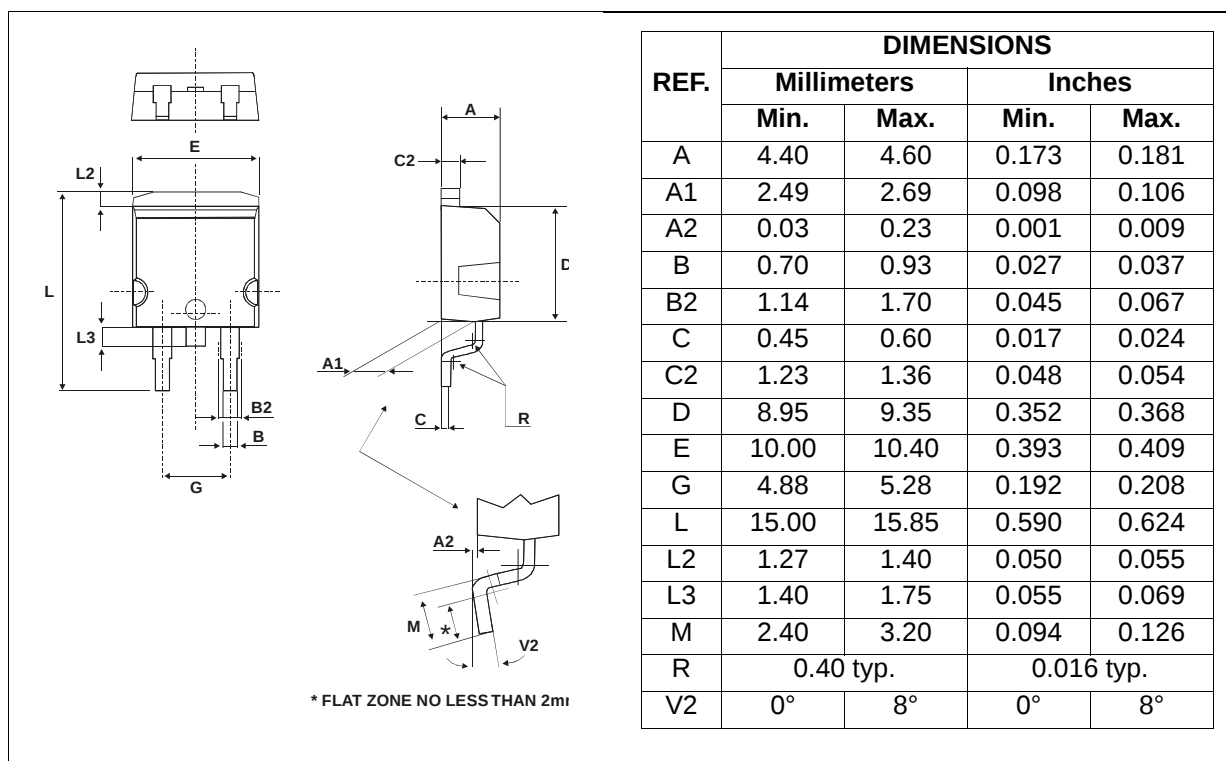
Figure 12: D²PAK Package Mechanical Data

Figure 13: Foot Print Dimensions (in millimeters)

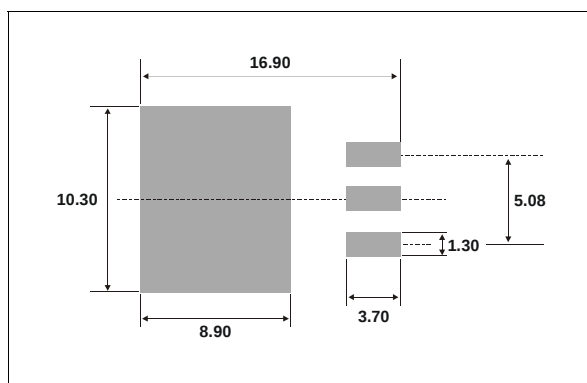


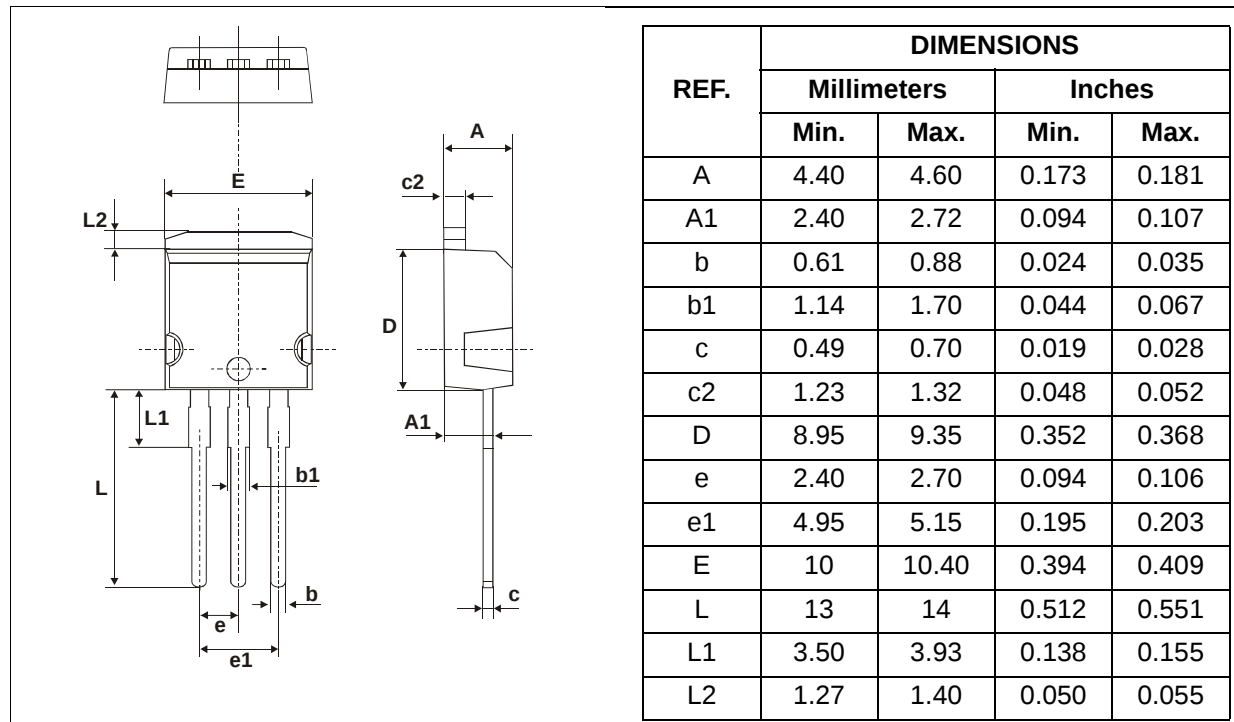
Figure 14: I²PAK Package Mechanical Data


Figure 15: TO-220FPAB Package Mechanical Data

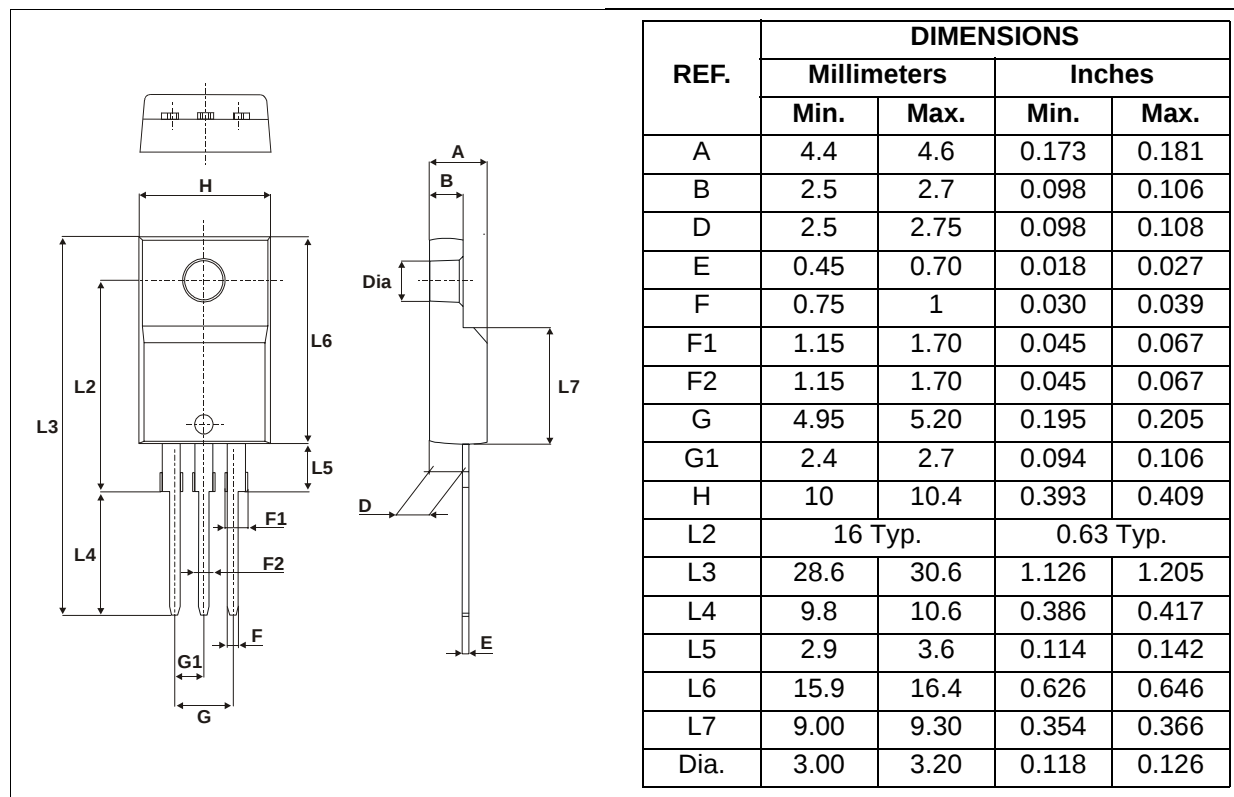


Figure 16: TO-220AB Package Mechanical Data

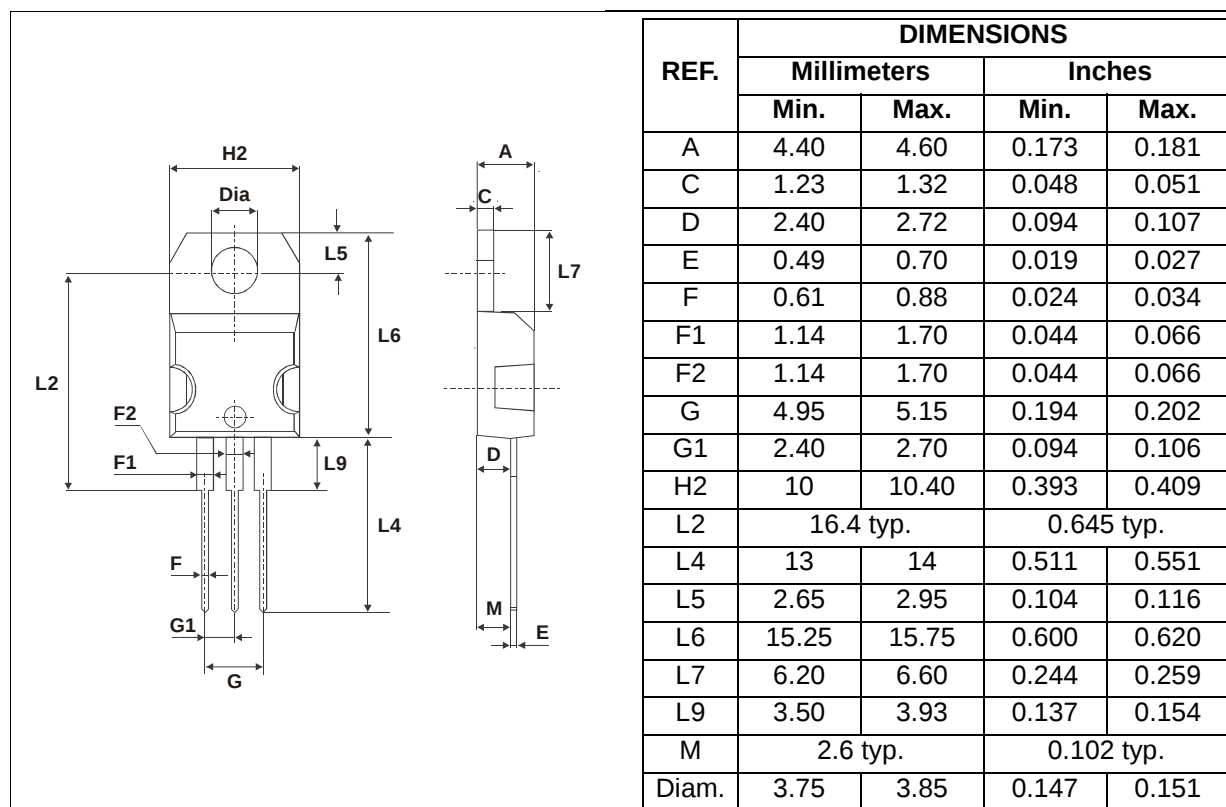


Table 6: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS20170CT	STPS20170CT	TO-220AB	2.20 g	50	Tube
STPS20170CFP	STPS20170CFP	TO-220FPAB	2 g	50	Tube
STPS20170CR	STPS20170CR	I ² PAK	1.49 g	50	Tube
STPS20170CG	STPS20170CG	D ² PAK	1.48 g	50	Tube
STPS20170CG-TR	STPS20170CG			1000	Tape & reel

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1.0 m.N.

Table 7: Revision History

Date	Revision	Description of Changes
Mar-2004	1	First issue.
28-Jul-2005	2	TO-220FPAB, I ² PAK and D ² PAK packages added.

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